

FORM PTO-1449 US Dept. of Commerce Patent and Trademark Office		ATTORNEY DOCKET NO. 249-Div.		SERIAL NO. TBA	
INFORMATION DISCLOSURE STATEMENT (use several sheets if necessary)		APPLICANT Thomas H. Baum, et al.			
		FILING DATE Herewith		GROUP TBA	

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U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	PATENT NUMBER	ISSUE DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
wm	AA	5,204,314	4/20/93	Kirlin, et al.	505	1	
	AB	5,225,561	7/6/93	Kirlin, et al.	546	256	
	AC	5,049,458	9/17/91	Sato, et al.	429	32	
	AD	5,045,169	9/3/91	Feduska, et al.	204	258	
	AE	4,937,152	6/26/90	Sato, et al.	429	30	
	AF	5,453,330	9/26/95	Kawasaki, et al.	429	30	
	AG	5,418,081	5/23/95	Kawasaki, et al.	429	33	
	AH	5,487,336	1/30/96	Li, et al.	117	99	
	AI	5,234,722	8/10/93	Ito, et al.	427	453	
	AJ	5,549,977	8/27/96	Jin, et al.	428	692	
	AK	5,792,569	8/11/98	Sun, et al.	428	692	
wm	AL	5,856,276	1/5/99	Koshy, et al.	505	239	

FOREIGN PATENT DOCUMENTS							
DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS S	TRANSLATION YES NO		
					X (abstract only)		
wm	AM	JP 4175226	6/23/92	Japan Name: Chisso Corp.			

OTHER DOCUMENTS (Including Author, Title, Journal-Date, Page Number, Etc.)	
wm	AN "Plasma Enhanced Metalorganic Chemical Vapor Deposition of Conductive Oxide Electrodes for Ferroelectric BaTiO ₃ Capacitors," J. Zhang, et al., Mater. Res. Soc. Symp. Proc. Vol. 310, <i>Ferroelectric Thin Films III</i> , E.R. Myers et al., editors, 1993, pp. 249-254.
	AO "Metal Organic Chemical Vapor Deposition of LaSrCoO Electrodes for Ferroelectric Capacitors." J. Zhang, et al., presented at the 6 th ISAF Meeting, March 1994.
wm	AP "Magnetoresistance in magnetic manganese oxide with intrinsic antiferromagnetic spin structure." K. Chahara, et al., Appl. Phys. Lett. 63, 1990-2 (1993).

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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

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09/26/01



OTHER DOCUMENTS (Including Author, Title, Journal-Date, Page Number, Etc.)

WM	AQ	"Giant negative magnetoresistance in perovskitelike $\text{La}_{2/3}\text{Ba}_{1/3}\text{MnO}_x$ ferromagnetic films." R. von Helmolt, et al., Phys. Rev. Lett. 71, 2331-3 (1993).
I	AR	Magnetic-Field-Induced metal-insulator phenomena in $\text{Pr}_{1-x}\text{Ca}_x\text{MnO}_3$ with controlled charge-ordering instability", Y. Tomioka, et al., Physical Review B. Vol. 53, Number-4, pp. 106-109, 1/1996.
I	AS	"Anomalous Magnetotransport Properties of $\text{Pr}_{1-x}\text{Ca}_x\text{MnO}_3$ ", Tomioka, et al., Journal of the Physical Society of Japan, Vol. 64, No. 10, pp. 3626-3630, 10/1995
WM	AT	"A First Order Phase Transition Induced by a Magnetic Field", Kuwahara, et al., Science, Vol. 270, pp. 961-963, 11/1995

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